Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

**Overall Length:** 

1.130 inches

**Mounting Facility Quantity:** 

1

Internal Configuration:

Junction contact

**Mounting Method:** 

Threaded stud

**Features Provided:** 

Hermetically sealed case

**Overall Width Across Flats:** 

1.062 inches

Thread Size:

0.500 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 repetitive peak reverse voltage and 100.0 repetitive peak off-state voltage

**Current Rating Per Characteristic:** 

80.00 amperes forward current, total rms horsepower metric

## Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector blank

**Special Features:** 

Junction pattern arrangement: pnpn

**Thread Series Designator:** 

Unf

**Terminal Type And Quantity:** 

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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